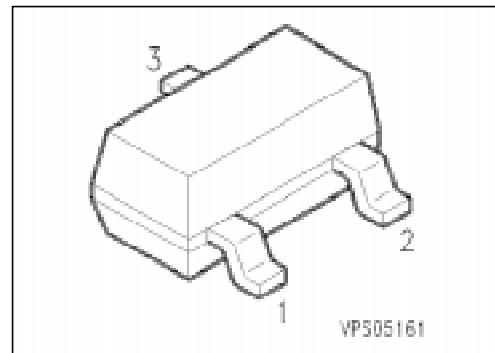


## Silicon Switching Diode

**SMBD 6050**

- For high-speed switching applications



Type	Marking	Ordering Code (tape and reel)	Pin Configuration	Package <sup>1)</sup>
SMBD 6050	s5A	Q68000-A8439		SOT-23

### Maximum Ratings

Parameter	Symbol	Values	Unit
Reverse voltage	$V_R$	70	V
Peak reverse voltage	$V_{RM}$	70	
Forward current	$I_F$	250	mA
Surge forward current, $t = 1 \mu s$	$I_{FS}$	4.5	A
Total power dissipation, $T_S = 54^\circ C$	$P_{tot}$	370	mW
Junction temperature	$T_J$	150	$^\circ C$
Storage temperature range	$T_{stg}$	- 65 ... + 150	

### Thermal Resistance

Junction - ambient <sup>2)</sup>	$R_{th JA}$	$\leq 330$	K/W
Junction - soldering point	$R_{th JS}$	$\leq 260$	

<sup>1)</sup> For detailed information see chapter Package Outlines.

<sup>2)</sup> Package mounted on epoxy pcb 40 mm × 40 mm × 1.5 mm/6 cm<sup>2</sup> Cu.

**Electrical Characteristics**at  $T_A = 25^\circ\text{C}$ , unless otherwise specified.

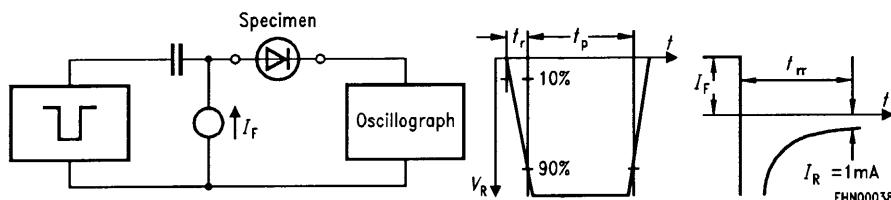
Parameter	Symbol	Values			Unit
		min.	typ.	max.	

**DC characteristics**

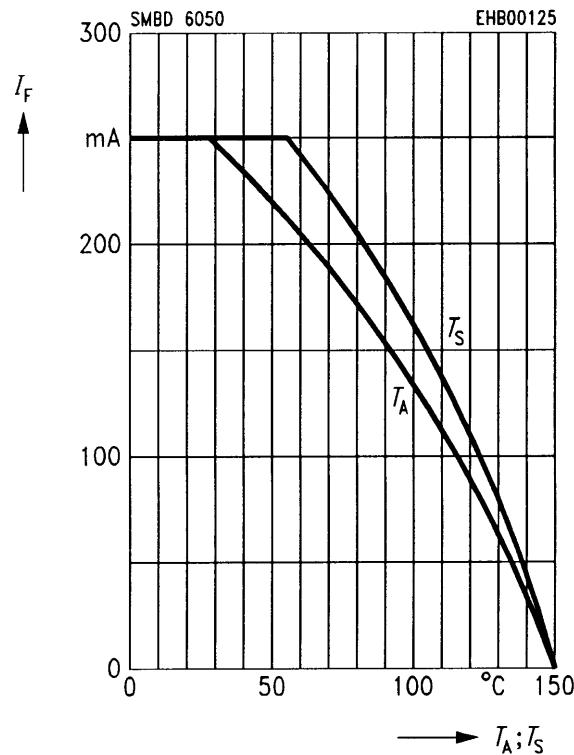
Breakdown voltage $I_{(\text{BR})} = 100 \mu\text{A}$	$V_{(\text{BR})}$	70	—	—	V
Forward voltage $I_F = 1 \text{ mA}$ $I_F = 100 \text{ mA}$	$V_F$	550	—	700	mV
Reverse current $V_R = 50 \text{ V}$	$I_R$	—	—	100	nA

**AC characteristics**

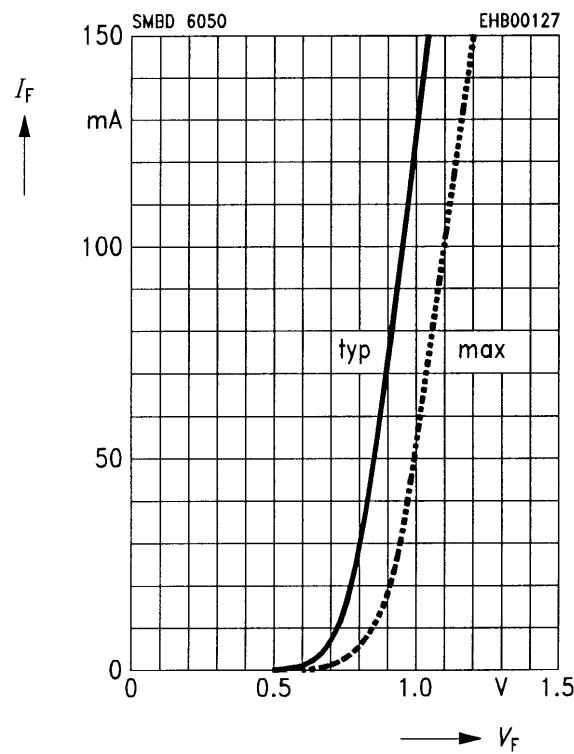
Diode capacitance $V_R = 0, f = 1 \text{ MHz}$	$C_D$	—	—	2.5	pF
Reverse recovery time $I_F = 10 \text{ mA}, I_R = 10 \text{ mA}, R_L = 100 \Omega$ measured at $I_R = 1 \text{ mA}$	$t_{rr}$	—	—	10	ns

**Test circuit for reverse recovery time**Pulse generator:  $t_p = 100 \text{ ns}$ ,  $D = 0.05$   
 $t_r = 0.6 \text{ ns}$ ,  $R_j = 50 \Omega$ Oscilloscope:  $R = 50 \Omega$   
 $t_r = 0.35 \text{ ns}$   
 $C \leq 1 \text{ pF}$

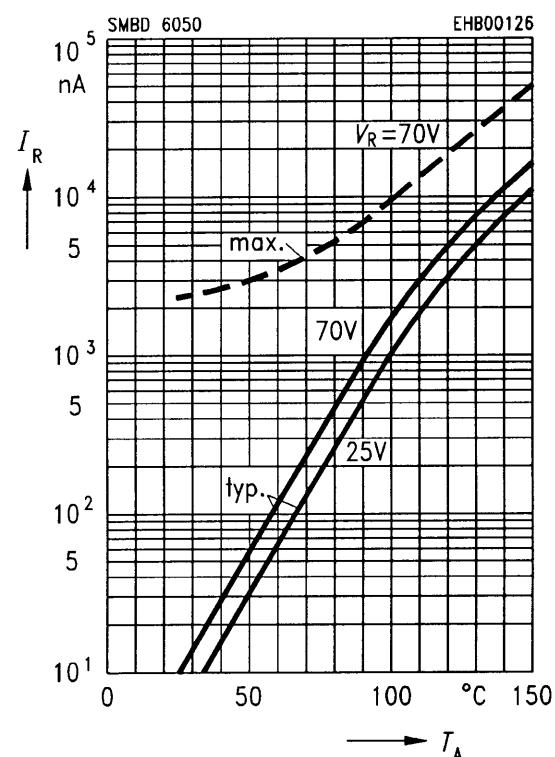
**Forward current  $I_F = f(T_A^*; T_S)$**   
 \* Package mounted on epoxy



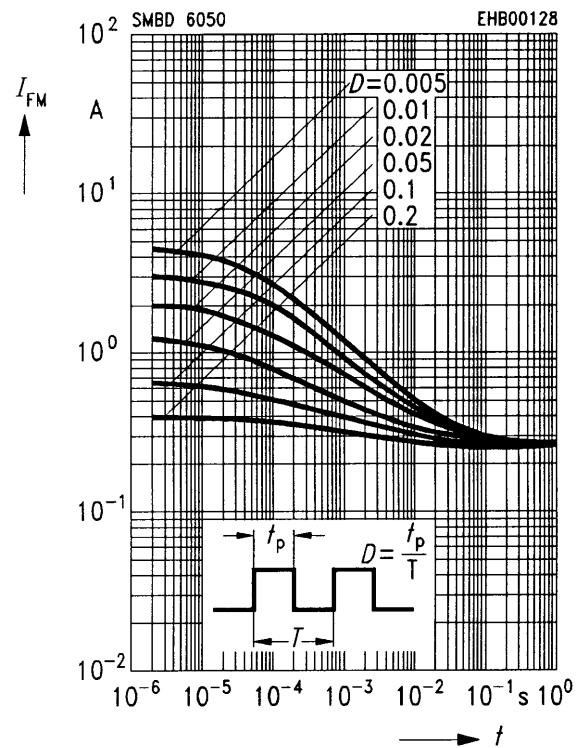
**Forward current  $I_F = f(V_F)$**   
 $T_A = 25^\circ\text{C}$



**Reverse current  $I_R = f(T_A)$**



**Peak forward current  $I_{FM} = f(t)$**   
 $T_A = 25^\circ\text{C}$



**Forward voltage  $V_F = f(T_A)$**

